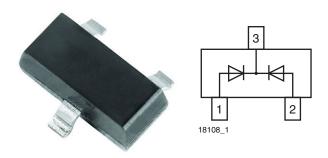
BAV23C

www.vishay.com

Vishay Semiconductors

Small Signal Switching Diode, Dual



DESIGN SUPPORT TOOLS click logo to get started



MECHANICAL DATA

Case: SOT-23 Weight: approx. 8.8 mg Packaging codes / options: 18/10K per 13" reel (8 mm tape), 10K/bo. 08/3K per 7" reel (8 mm tape), 15K/box

FE/	ATU	RES

- Silicon epitaxial planar diode
- Fast switching dual diode with common cathode
- AEC-Q101 qualified available
- Base P/N-E3 RoHS-compliant, commercial grade
- Base P/N-HE3 RoHS-compliant, AEC-Q101 qualified
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>



ROHS COMPLIANT

ptions:			
mm tape), 10K/box			
m tape), 15K/box			
ORDERING CODE	CIRCUIT CONFIGURATION	TYPE MARKING	REMAR

PARTS TABLE						
PART	ORDERING CODE	CIRCUIT CONFIGURATION	TYPE MARKING	REMARKS		
BAV23C	BAV23C-E3-08 or BAV23C-E3-18	Common cathode	KT6	Tapo and rool		
BAV23C	BAV23C-HE3-08 or BAV23C-HE3-18	Common Cathode	KIU	Tape and reel		

ABSOLUTE MAXIMUM RATINGS (T _{amb} = 25 °C, unless otherwise specified)					
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT	
Continuous reverse voltage		V _R	200	V	
Repetitive peak reverse voltage		V _{RRM}	250	V	
Non-repetitive peak forward current	t = 1 µs	I _{FSM}	9	A	
Non-repetitive peak forward surge current	t = 1 s	I _{FSM}	0.5	A	
Maximum average forward rectified current (1)		I _{F(AV)}	200	mA	
Forward continuous current ⁽²⁾		I _F	400	mA	
Repetitive peak forward current		I _{FRM}	625	mA	
Power dissipation ⁽²⁾		P _{tot}	350	mW	

Notes

⁽¹⁾ Measured under pulse conditions; pulse time = $t_p \le 0.3$ ms

⁽²⁾ Device on fiberglass substrate

THERMAL CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified)					
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT	
Thermal resistance junction to ambient air ⁽¹⁾		R _{thJA}	357	K/W	
Junction temperature		Tj	150	°C	
Storage temperature range		T _{stg}	-65 to +150	°C	
Operating temperature range		T _{op}	-55 to +150	°C	

Note

⁽¹⁾ Device on fiberglass substrate

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ELECTRICAL CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified)						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Reverse breakdown voltage	$I_R = 100 \ \mu A, t_p = 300 \ ms$	V _(BR)	250			V
Forward voltage	I _F = 100 mA	V _F			1	V
	I _F = 200 mA	V _F			1.25	V
Reverse current	V _R = 200 V	I _R			100	nA
	$V_R = 200 \text{ V}, \text{ T}_j = 150 ^\circ\text{C}$	I _R			100	μA
Dynamic forward resistance	I _F = 10 mA	r _f		5		Ω
Diode capacitance	$V_R = 0 V$, f = 1 MHz	CD			5	pF
Reverse recovery time	$I_{F} = I_{R} = 30 \text{ mA}, R_{L} = 100 \Omega$ $i_{R} = 3 \text{ mA}$	t _{rr}			50	ns

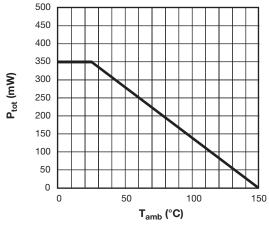


Fig. 1 - P_{tot} - Admissible Power Dissipation vs. Ambient Temperature

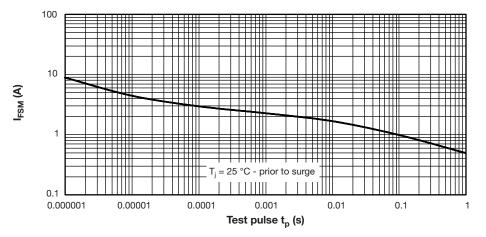


Fig. 2 - I_{FSM} - Non-Repetitive Peak Forward Current vs. Pulse Duration - Maximum Admissible Values of Square Pulses

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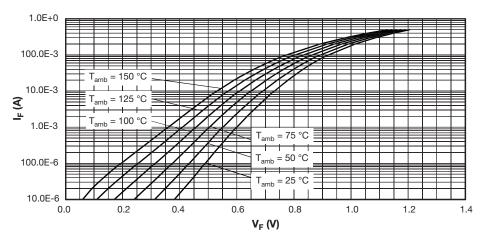


Fig. 3 - V_F - Typical Forward Current vs. Forward Voltage vs. Various Temperatures

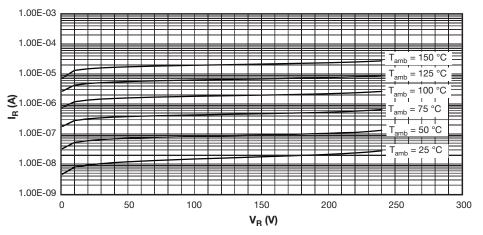
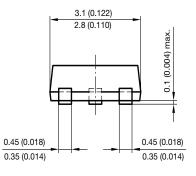


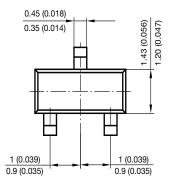
Fig. 4 - I_R - Typical Reverse Current vs. Reverse Voltage vs. Various Temperatures



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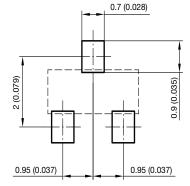
PACKAGE DIMENSIONS in millimeters (inches): SOT-23





0.550 ref. (0.022 ref.) 1.15 (0.045) 0.9 (0.035) 0.175 (0.007) 0.098 (0.004) 0.2 (0.008) å 0° to e 0.5 (0.020) 0.3 (0.012) 2.6 (0.102) 2.35 (0.093)

Foot print recommendation:



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